

UNITED STATES PATENT AND TRADEMARK OFFICE
CERTIFICATE OF CORRECTION

PATENT NO. : 7,737,012 B2
APPLICATION NO. : 10/557746
DATED : June 15, 2010
INVENTOR(S) : Satoshi Shibata

Page 1 of 1

It is certified that error appears in the above-identified patent and that said Letters Patent is hereby corrected as shown below:

ON THE TITLE PAGE:

In Item “(56) References Cited”, under “OTHER PUBLICATIONS” and
before the Examiner Information, insert the following:

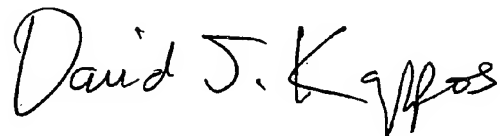
-- BORLAND “Low Temperature Activation of Ion

Implanted Dopants: A Review”, Japan Society of

Applied Physics, 202, pp. 85-88 --

Signed and Sealed this

Twelfth Day of October, 2010

A handwritten signature in black ink, reading "David J. Kappos". The signature is written in a cursive, flowing style with a large, stylized 'D' and 'K'.

David J. Kappos
Director of the United States Patent and Trademark Office